# **AN1101SSM**

## CMOS single power supply

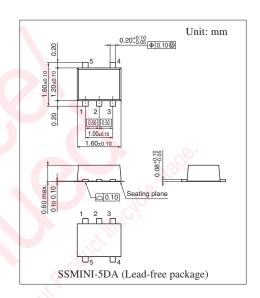
#### Overview

AN1101SSM is an operational amplifier with a single power supply by CMOS diffusion process.

It has low current-consumption compared to general purpose operational amplifier by bipolar diffusion process. 0 V to  $V_{DD}$  is available for both input voltage and output voltage. And this IC is widely applicable to the buttery-driven equipment and to many amplifier circuits which adopt small package products.

#### ■ Features

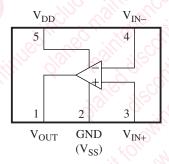
- Low current-consumption:  $I_{DD} = 55 \mu A$  (typ.),  $V_{DD} = 3 V$
- Operating input/output voltage range: 0 V to V<sub>DD</sub>
- Small offset voltage: 0.5 mV (typ.)
- Small input bias current: 1 pA (typ.)
- Operating supply voltage range:
  2.5 V to 5.5 V or ±1.25 V to ±2.75 V



### Applications

• Various small-size general consumer electronics equipment

### ■ Block Diagram



### ■ Pin Descriptions

Pin No.	Symbol	Description				
1	V <sub>OUT</sub>	Output				
2	GND (V <sub>SS</sub> )	Ground, $V_{SS}$ (negative supply) at using two power supply				
3	V <sub>IN+</sub>	Input (positive)				
4	$V_{IN-}$	Input (negative)				
5	$V_{\mathrm{DD}}$	Power supply				

Note) The AN1101SSM has been designed for general consumer electronics equipment, not for the specific one requiring such a high reliability that may prevent it from threatening the human lives.

### ■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	$V_{DD}$	5.6	V
Differential input voltage	DV <sub>IN</sub>	±5.6	V
Input voltage	V <sub>IN</sub>	$ m V_{SS}$ to $ m V_{DD}$	V
Supply current	$I_{DD}$	_	mA
Power dissipation *2	$P_{\mathrm{D}}$	50	mW
Operating ambient temperature *1	T <sub>opr</sub>	-30 to +85	°C
Storage temperature *1	T <sub>stg</sub>	-55 to +125	°C

Note) 1. \*1: Except for the operating ambient temperature and storage temperature, all ratings are for  $T_a = 25^{\circ}$ C.

### ■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	$V_{\mathrm{DD}}$	2.5 to 5.5	V
		±1.25 to ±2.75	

### ■ Electrical Characteristics at V<sub>DD</sub> = 3.0 V, V<sub>SS</sub> = GND, T<sub>a</sub> = 25°C ± 2°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input offset voltage	V <sub>IO</sub>	Buffer circuit	9—	0.5	5.5	mV
Common-mode input voltage	CMV <sub>IN</sub>	$R_S = 10 \text{ k}\Omega, R_F = 10 \text{ k}\Omega$	0	3	3	V
Open-loop gain	GV	f = 100 Hz	60	90	2 <del>0.</del> 2.	dB
Maximum output amplitude voltage 1	V <sub>OH</sub>	$R_L \ge 10 \text{ k}\Omega$	2.90	2.98	_	V
Maximum output amplitude voltage 2	V <sub>OL</sub>	$R_L \ge 10 \text{ k}\Omega$	2	0.01	0.05	V
Common-mode input voltage rejection ratio	CMRR	$V_{IN} = 0.0 \text{ V to } 3.0 \text{ V}, R_S = R_F = 10 \text{ k}\Omega$	50	65	_	dB
Supply voltage ripple rejection ratio *	SVRR	$V_{DD} = 2.5 \text{ V to } 5.5 \text{ V}$	55	70	_	dB
Supply current	$I_{DD}$	No load		55	100	μΑ

Note) \* : Except for the supply voltage ripple rejection ratio (SVRR),  $V_{DD}$  = 3 V.

### • Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Reference	Unit
Offset current	I <sub>O</sub>	_	1	pA
Input bias current	I <sub>IO</sub>		1	pA
Slew rate	SR	$R_L \ge 10 \text{ k}\Omega$	0.35	V/µs
Zero-cross frequency	$f_T$	$A_V = 1$	0.8	MHz

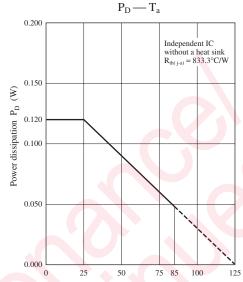
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<sup>\*2:</sup> The value at  $T_a = +85$ °C.

<sup>2.</sup> This IC is not suitable for car electrical equipment.

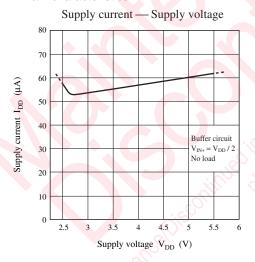
#### ■ Technical Data

• P<sub>D</sub> — T<sub>a</sub> curve of SSMINI-5DA

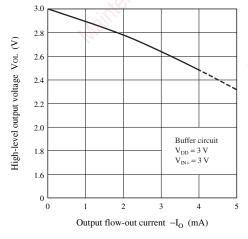


Main characteristics

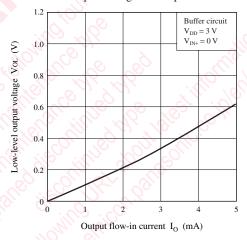
Ambient temperature T<sub>a</sub> (°C)



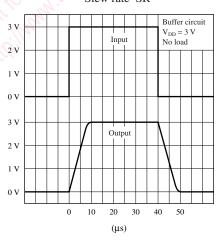
High-level output voltage — Output flow-out current



Low-level output voltage — Output flow-in current



Slew rate SR

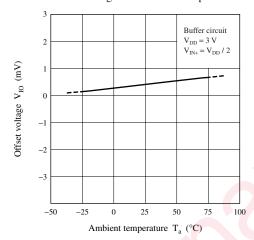


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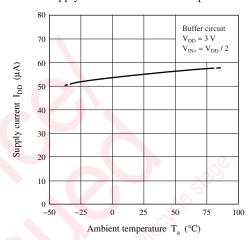
### ■ Technical Data (continued)

• Main characteristics (continued)

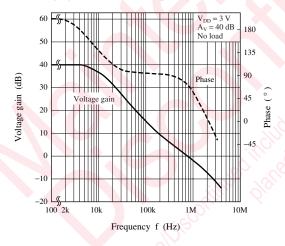
Offset voltage — Ambient temperature



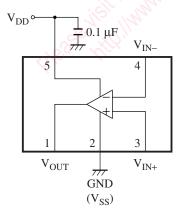
Supply current — Ambient temperature



Voltage gain · Phase — Frequency characteristics



### ■ Application Circuit Example



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